

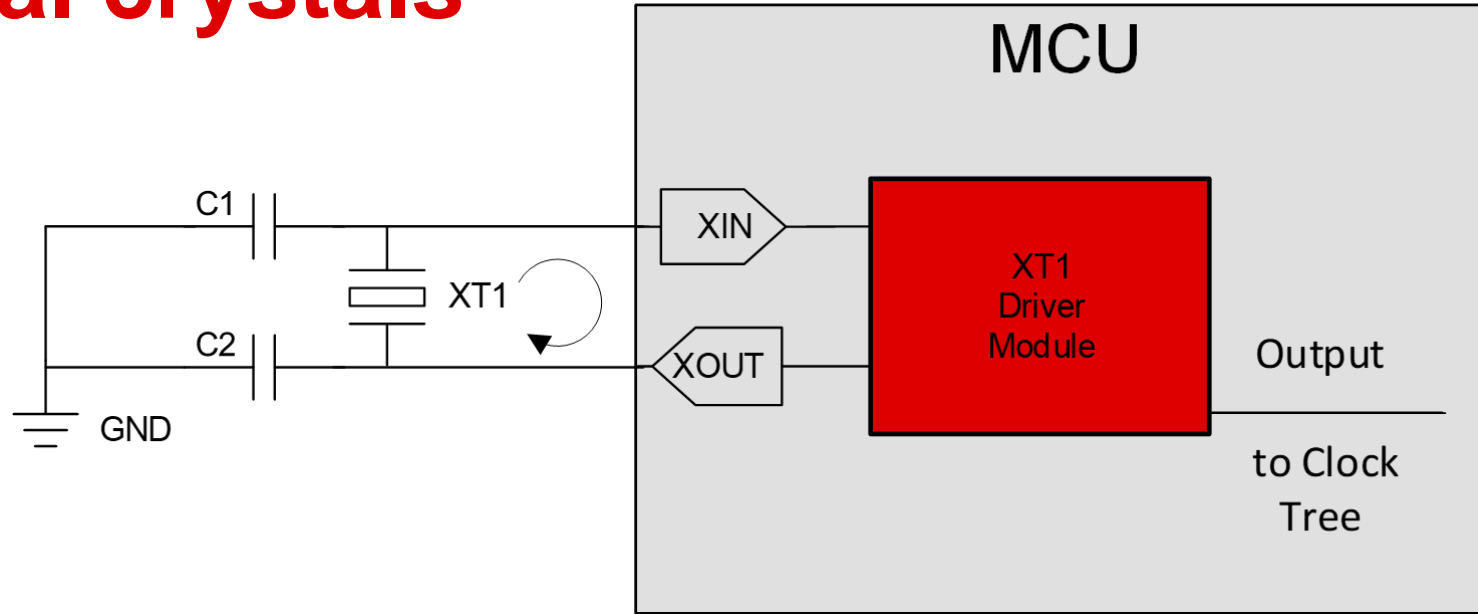
# Selecting an External Crystal

TI Precision Labs – Microcontrollers

Presented by Henok Taffere

Prepared by Brandon Fisher

# External crystals



- More accurate with less drift over operating conditions
- Lower power consumption than internal sources
- Long startup time
- Frequency is set by source
- Added system cost
- Needs special board layout considerations to operate properly

# External crystal accuracy

## Internal Oscillator Specification

PARAMETER		TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
I <sub>REFO</sub>	REFO oscillator current consumption	T <sub>A</sub> = 25°C	1.8 V to 3.6 V		3		μA
f <sub>REFO</sub>	REFO frequency calibrated	Measured at ACLK	1.8 V to 3.6 V		32768		Hz
	REFO absolute tolerance calibrated	Full temperature range T <sub>A</sub> = 25°C	1.8 V to 3.6 V 3 V			±3.5% ±1.5%	

$$F_{RANGE} = 32768 \text{ Hz} \pm 491.52 \text{ Hz}$$

## External Oscillator Specification

Parameters	Min	TYP	MAX	Units
Frequency Tolerance @ +25°C	-10		+10	ppm

**Note:** 1 ppm = 0.0001%

$$F_{RANGE} = 32768 \text{ Hz} \pm 0.33 \text{ Hz}$$

$$Error_{RTC} = \frac{24 \text{ hr}}{\text{day}} * \frac{60 \text{ m}}{\text{hour}} * \frac{60 \text{ s}}{\text{m}} * Error_{CLK}$$

$$Error_{RTC} = 86400 \frac{\text{s}}{\text{day}} * \frac{1.5}{100} \cong 21.5 \frac{\text{minutes}}{\text{day}}$$

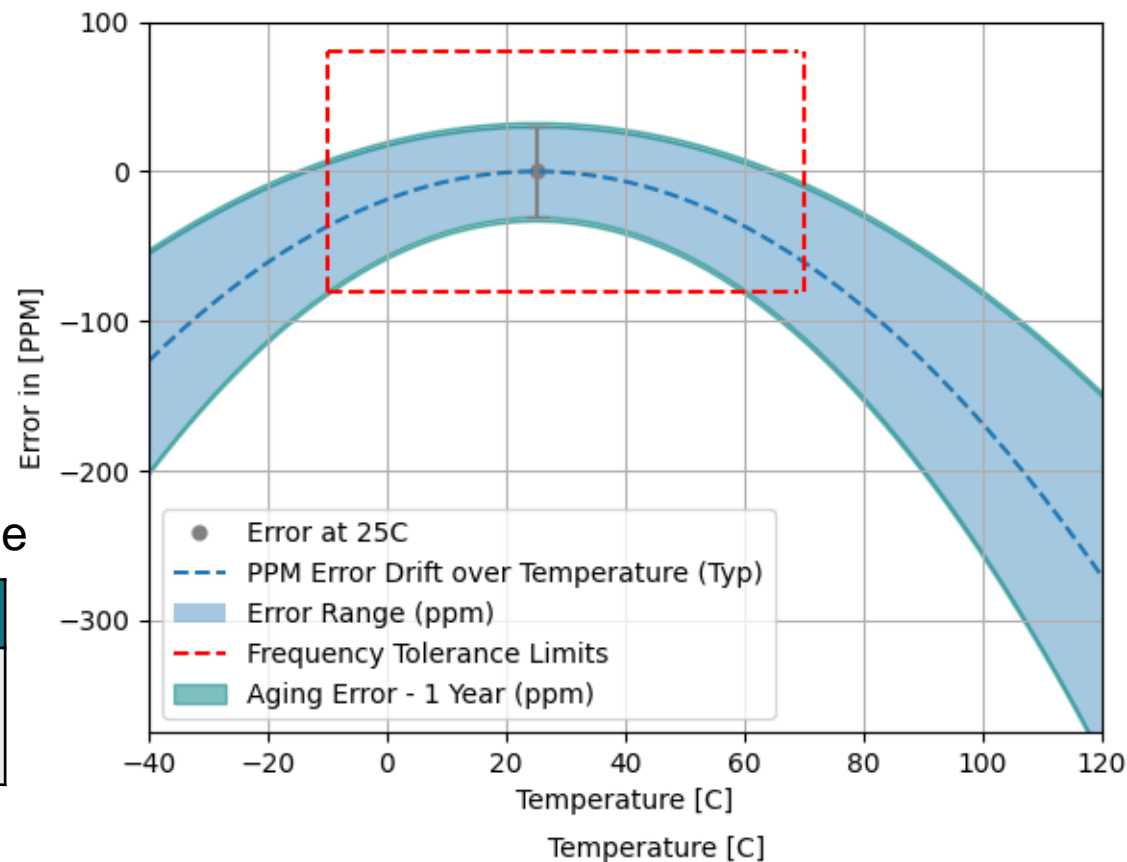
$$Error_{RTC} = 86400 \frac{\text{s}}{\text{day}} * \frac{10}{10^6} = 0.864 \frac{\text{seconds}}{\text{day}}$$

# Accuracy stability and drift

Parameters	Conditions	Min	TYP	MAX	Units
Frequency		3.57		70.000	MHz
Frequency Tolerance	25°C			±30	ppm
Temperature Coefficient		-0.04	-0.03	-0.02	ppm/T <sup>2</sup>

Frequency Tolerance is sometimes given a temperature range

Parameters	Conditions	Min	TYP	MAX	Units
Frequency Tolerance	25°C			±30	ppm
	-10 ~ + 70 °C			±80	

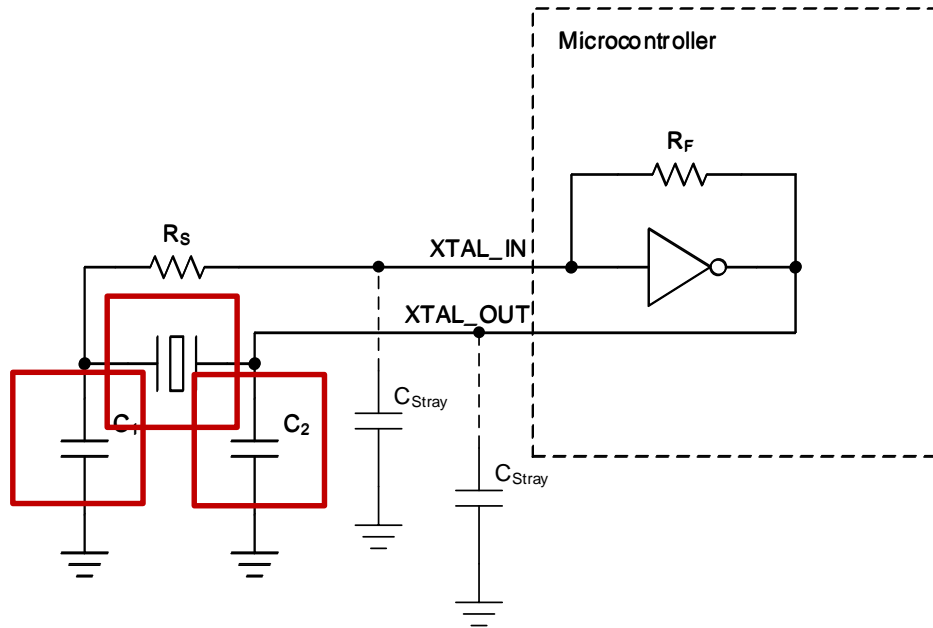


Crystals also drift over time, the rate at which they drift is often given as “Aging”

Parameter	MAX	Units
Aging	±3	ppm/year

# Load capacitance

Parameters	MIN	TYP	MAX	Units
Load Capacitance ( $C_L$ )		12		pF



In the Ideal Case: 
$$C_L = \frac{C_1 * C_2}{C_1 + C_2}$$

Really: 
$$C_L = \frac{C'_1 * C'_2}{C'_1 + C'_2}$$
 Where:  $C'_x = C_x + C_{Stray}$

In most cases, we choose  $C_1 = C_2$ : So: 
$$C_L = \frac{C_1 + C_{Stray}}{2}$$

For this example:

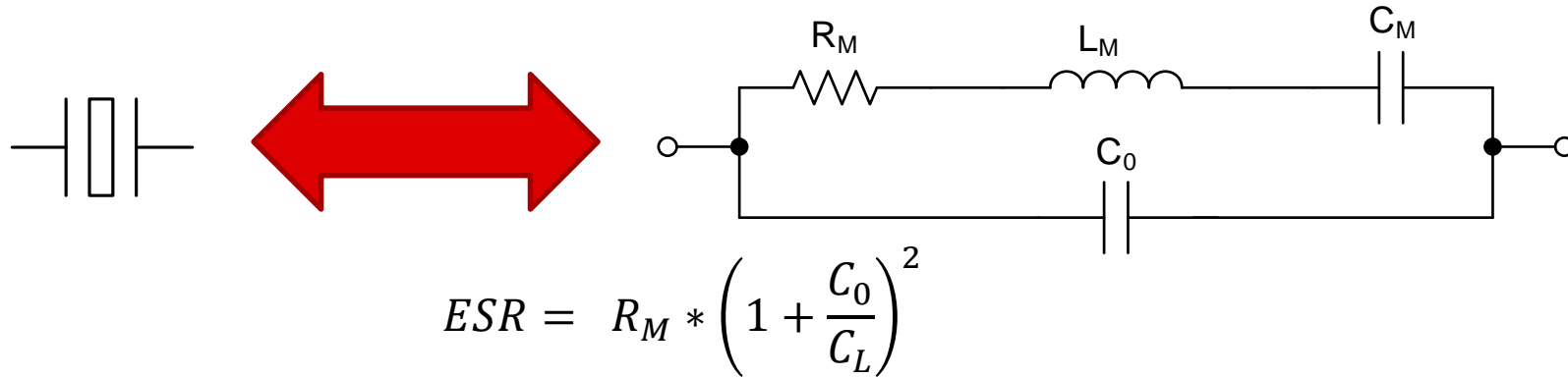
$$C_1 = C_2 = 22\text{pF} \text{ if } C_{stray} = 2\text{pF}$$

We can check if this is right:

$$C_L = \frac{C_1 + C_{Stray}}{2} = \frac{22\text{pF} + 2\text{pF}}{2}$$

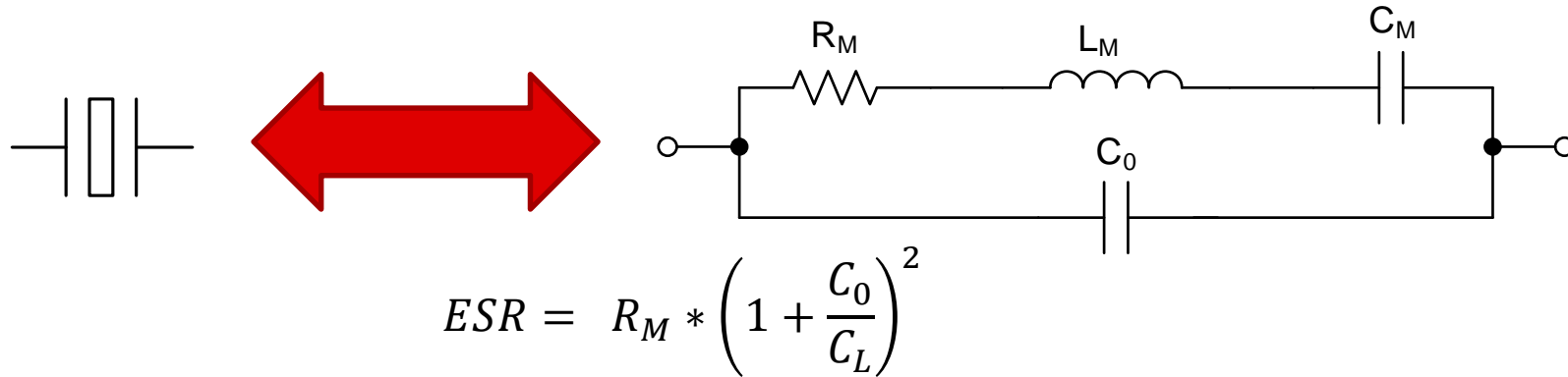
$$C_L = 12\text{pF}$$

# Equivalent series resistance

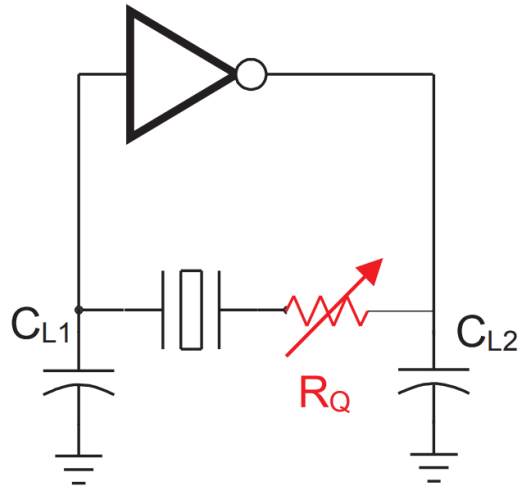


Design Parameter	Higher ESR Crystal	Lower ESR Crystal
Safety Factor	❌ Worse	✅ Better
Startup Time	❌ Worse	✅ Better
Power Dissipation	❌ Worse	✅ Better
Peak Drive Level	❌ Worse	✅ Better
Cost	✅ Better	❌ Worse
PCB Footprint	✅ Better	❌ Worse

# Equivalent series resistance



How do you know how high of an ESR Value is too high?



Oscillation Allowance (OA) OR Negative Resistance = Test Crystal ESR +  $R_Q$

$$\text{Safety Factor (SF)} = \frac{OA}{ESR}$$

Safety Factor	Qualification
SF < 2	Unsafe
2 ≤ SF < 3	Suitable
3 ≤ SF < 5	Safe
SF ≥ 5	Very Safe

To find more TI microcontroller technical resources and search products, visit [ti.com/Microcontrollers](https://www.ti.com/Microcontrollers).